

High Reliability Serial EEPROMs

Microwire BUS BR93□□□family



BU9888FV-W No.11001EAT20

Description

BU9888FV-W is a serial EEPROM of serial 3-line interface method.

Features

- 1) 256word×16bits architecture 4k bit serial EEPROM
- 2) Operating voltage range(3.0~3.6V)
- 3) Address auto increment function at read action
- 4) Write mistake prevention function
 - Write prohibition at power on
 - Write prohibition by command code
 - Write mistake prevention function at low voltage
- 5) Program cycle auto delete and auto end function
- 6) Program condition display READY / BUSY
- 7) Low current consumption

At write action(3.6V): Icc1 = 3.5mA(Max.)At read action(3.6V): Icc2 = 2.0mA(Max.)At standby action (3.6V): $ISB = 2.0\mu A(Max.)$

- 8) Compact package SSOP-B8pin
- 9) Data retention for 40 years
- 10) Data rewrite up to 100,000 times
- 11) Data at shipment all addresses FFFFh

● Absolute maximum rating (Ta=25°C)

Parameter	Symbol	Symbol Ratings	
Supply Voltage	Vcc -0.3~+6.5		V
Power Dissipation	Pd	300 *1	
Storage Temperature	Tstg	-65 ~ +125	°C
Operating Temperature	Topr	-20 ~ +85	°C
Terminal Voltage	_	-0.3~Vcc+0.3 *2	V

^{*1} Degradation is done at 3.0mW/°C for operation above 25°C

●EEPROM recommended operating condition

Parameter	Symbol	Ratings	Unit
Supply Voltage	Vcc	3.0~3.6	W
Input Voltage	VIN	0 ~ Vcc	V

●Memory cell characteristics(Ta=25°C, Vcc = 3.0~3.6V)

Parameter	Limits			Unit
Farameter	Min.	Тур.	Max.	Offic
Erase/Write Cycle *1	100,000	-	_	Cycles
Data Retention *1	40	_	_	Years

^{*1} Not 100% TESTED

^{*2} The Max value of Terminal Voltage is not over 6.5V

●DC Operating Characteristics(Unless otherwise specified Ta=-20~+85°C, Vcc=3.0~3.6V)

Parameter	Symbol	Limits			Unit	Test Condition
Farameter	Symbol	Min.	Тур.	Max.	Offic	rest Condition
"L" Input Voltage	VIL	-0.3	_	0.2×Vcc	V	
"H" Input Voltage	VIH	0.8×Vcc	_	Vcc+0.3	V	
"L" Output Voltage	VOL	0	_	0.4	V	IOL=2.1mA
"H" Output Voltage	VOH	2.4	_	Vcc	V	IOH=-0.4mA
Input Leakage Current	ILI	-1	_	1	μΑ	VIN=0~Vcc
Output Leakage Current	ILO	-1	_	1	μA	VOUT=0~Vcc, CS=0V
Operating Current	ICC1	_	_	3.5	mA	fSK=2MHz, tE/W=2ms(WRITE), TEST1=Vcc
Operating Current	ICC2	_	_	2.0	mA	fSK=2MHz, (READ), TEST1=Vcc
Standby Current	ISB	_	_	2.0	μΑ	CS=0V, TEST1=Vcc, DO=OPEN

OThis product is not designed for protection against radioactive rays.

●EEPROM AC Operating Characteristics (Ta=-20~+85°C, Vcc = 3.0~3.6V)

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Paramete	Symbol	Limits			Unit
Faiaillete	Syllibol	Min.	Тур.	Max.	Offic
SK Clock Frequency	fSK	_	_	2	MHz
SK High Time	tSKH	230	_	_	ns
SK Low Time	tSKL	230	_	_	ns
CS Low Time	tCS	200	_	_	ns
CS Setup Time	tCSS	200	_	_	ns
DI Setup Time	tDIS	100	_	_	ns
CS Hold Time	tCSH	0	_	_	ns
DI Hold Time	tDIH	100	_	_	ns
Data "1" Output Delay Time	tPD1	_	_	200	ns
Data "0" Output Delay Time	tPD0	_	_	200	ns
CS to Status Valid	tSV	_	_	150	ns
CS to Output High-Z	tDF	_	_	150	ns
Write Cycle time	tE/W	_	_	2	ms

Synchronous data input/output timing

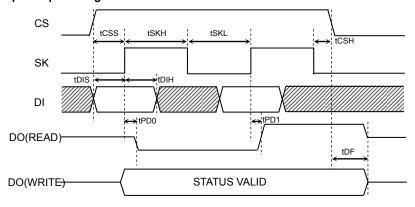
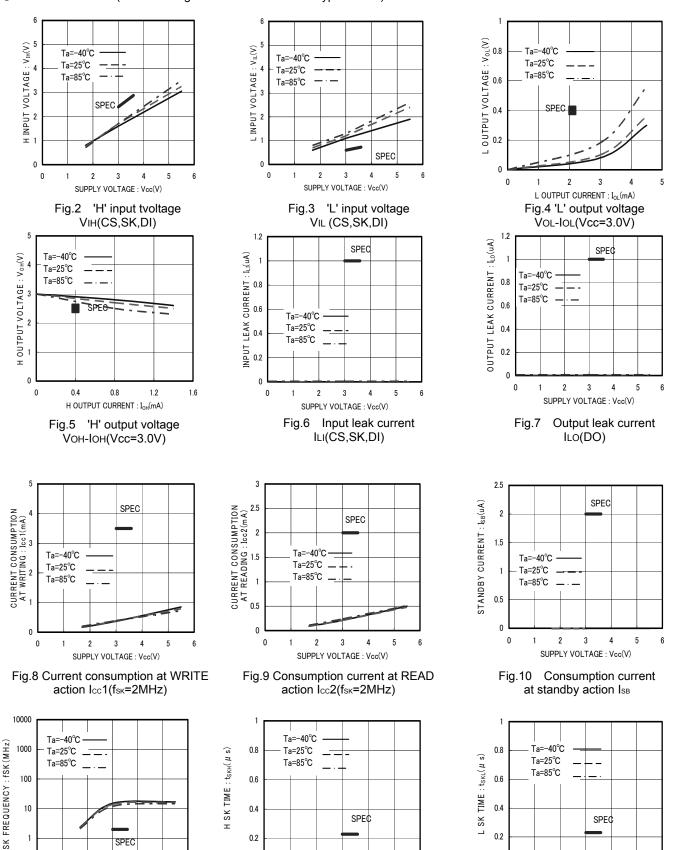


Fig.1 Sync data input / output timing

- OData is taken by DI in sync with the rise of SK.
- OAt read action, data is output from DO in sync with the rise of SK.
- OThe status signal at write (READY / BUSY) is output after tCS from the fall of CS after write command input, at the area DO where CS is "H", and valid until the next command start bit is input. And, while CS is "L", DO becomes High-Z.
- OAfter completion of each mode execution, set CS "L" once for internal circuit reset, and execute the following action mode.

● Characteristic data (The following characteristic data are Typ. Values.)



2 3 4 5

SUPPLY VOLTAGE : Vcc(V)

1 SK frequency fsk

0.1

Fig.11

SUPPLY VOLTAGE: Vcc(V)

Fig.12 SK high time tsкн

2 3 4

0

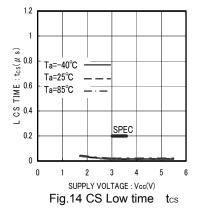
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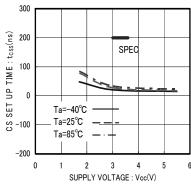
2

SUPPLY VOLTAGE: Vcc(V)

Fig.13 SK low time tSKL

● Characteristic data (The following characteristic data are Typ. Values.)





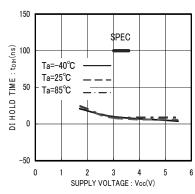
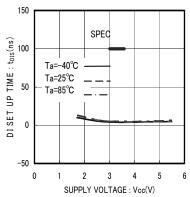
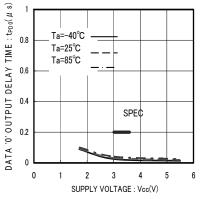


Fig.15 CS Setup time tcss

Fig.16 DI Hold time tDIH





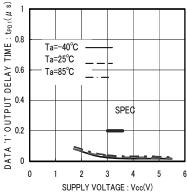
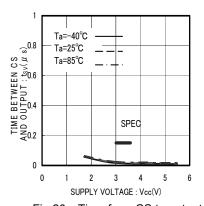
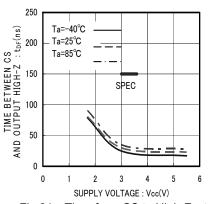


Fig.17 DI Setup time tois

Fig.18 Data '0' output delay time tPD0

Fig.19 Data '1' output delay time tPD1





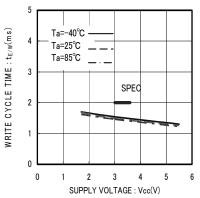


Fig.20 Time from CS to output establishment tsv

Fig.21 Time from CS to High-Z tDF

Fig.22 Write cycle time tE/W

●Pin assignment

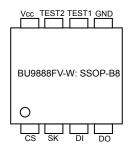


Fig.23 Pin assignment diagram

Pin function

Pin name	1/0	Function		
CS	Input	Chip select input		
SK	Input	Serial clock input		
DI	Input	Serial data input		
DO	Output	Serial data output		
TEST1	Input	Test pin. Please connect to power.		
TEST2	-	Test pin. Please open at using.		
Vcc	-	Power source		
GND	-	All input / output reference voltage, 0V		

Block diagram

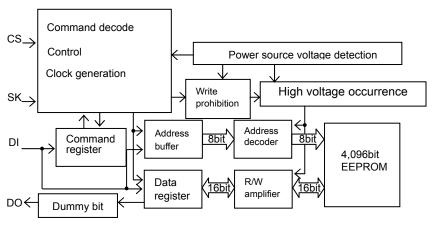


Fig.24 Block diagram

●Command mode

Command	Start bit	Ope code	Address	Data
Read (READ)	1	10	A7, A6, A5, A4, A3, A2,A1, A0	D15~D0(READ DATA)
Write enable (WEN)	1	00	1 1 * * * * * *	
Write (WRITE)	1	01	A7, A6, A5, A4, A3, A2, A1, A0	D15~D0(WRITE DATA)
Write disable (WDS)	1	00	0 0 * * * * * *	

- Input the address and the data in MSB first manners.
- As for *, input either VIH or VIL.

*Start bit

Acceptance of all the commands of this IC starts at recognition of the start bit.

The start bit means the first "1" input after the rise of CS.

- *1As for read, by continuous SK clock input after setting the read command, data output of the set address starts, and address data in significant order are sequentially output continuously. (Auto increment function)
- *2When the read and the write all commands are executed, data written in the selected memory cell is automatically deleted, and input data is written.

BU9888FV-W

Timing chart

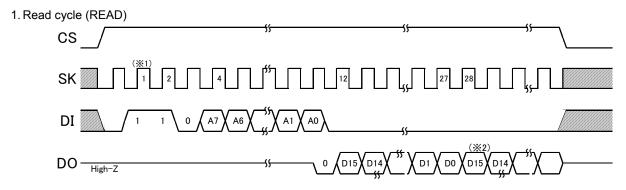


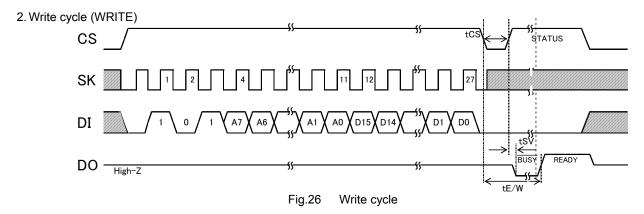
Fig.25 Read cycle

(※2) Next address data(Auto increment function)

(%1) Start bit

When data "1" is input for the first time after the rise of CS, this is recognized as a start bit. And when "1" is input after plural "0" are input, it is recognized as a start bit, and the following operation is started. This is common to all the commands to described hereafter.

OWhen the read command is recognized, input address data (16bit) is output to serial. And at that moment, at taking A0, in sync with the rise of SK, "0" (dummy bit) is output. And, the following data is output in sync with the rise of SK. This IC has an address auto increment function valid only at read command. This is the function where after the above read execution, by continuously inputting SK clock, the above address data is read sequentially. And, during the auto increment, keep CS at "H".



OIn this command, input 16bit data (D15~D0) are written to designated addresses (A7~A0). The actual write starts by the fall of CS of D0 taken SK clock. When STATUS is not detected, (CS="L" fixed) Max. 2ms in conformity with tE/W, and when STATUS is detected (CS="H"), all commands are not accepted for areas where "L" (BUSY) is output from D0, therefore, do not input any command.

3. Write enable (WEN)

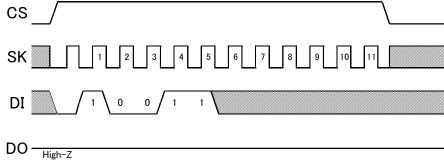


Fig.27 Write enable (WEN) cycle

OAt power on, this IC is in write disable status by the internal RESET circuit. Before executing the write command, it is necessary to execute the write enable command. And, once this command is executed, it is valid until the write disable command is executed or the power is turned off. However, the read command is valid irrespective of write enable / diable command. Input to SK after 8 clocks of this command is available by either "H" or "L", but be sure to input it.

4. Write disable (WDS) cycle

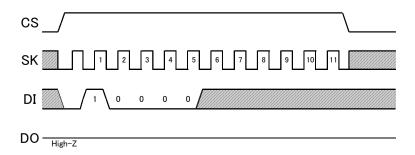
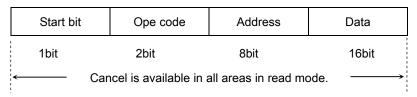


Fig.28 Write disable (WDS) cycle

OWhen the write enable command is executed after power on, write enable status gets in. When the write disable command is executed then, the IC gets in write disable status as same as at power on, and then the write command is canceled thereafter in software manner. However, the read command is executable. In write enable status, even when the write command is input by mistake, write is started. To prevent such a mistake, it is recommended to execute the write disable command after completion of write. Input to SK after 8 clocks of this command is available by either "H" or "L", but be sure to input it.

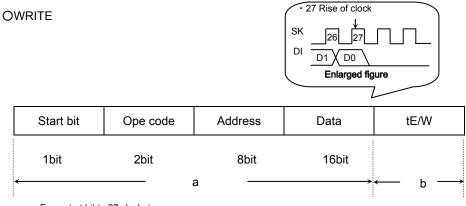
Application

1)Method to cancel each command OREAD



•Method to cancel:cancel by CS="L"

Fig.29 READ cancel available timing



a:From start bit to 27 clock rise Cancel by CS="L"

b:27 clock rise and after

Cancellation is not available by any means. If Vcc is made OFF in this area, designated address data is not guaranteed, therefore write once again.

And when SK clock is input continuously, cancellation is not available.

Fig.30 Write cancel available timing

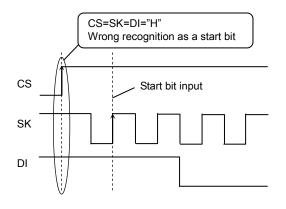
2) At standby

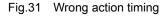
OStandby current

When CS is "L", SK input is "L", DI input is "H", and even with middle electric potential, current does not increase.

OTiming

As shown in Fig.31, when SK at standby is "H", if CS is started, DI status may be read at the rise edge. At standby and at power ON/OFF, when to start CS, set SK input or DI input to "L" status. (Refer to Fig.32)





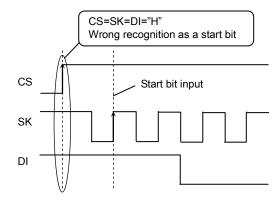


Fig.32 Normal action timing

3) Equivalent circuit

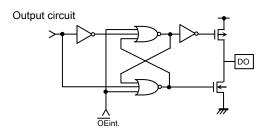


Fig.33 Output circuit (DO)

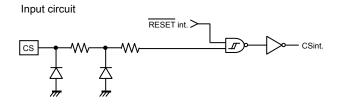


Fig.34 Input circuit (CS)

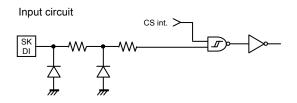


Fig.35 Input circuit (SK,DI)

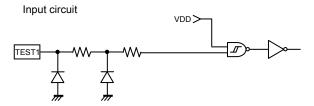


Fig.36 Input circuit (TEST1)

4) I/O peripheral circuit

4-1) Pull down CS.

By making CS="L" at power ON/OFF, mistake in operation and mistake write are prevented.

OPull down resistance Rpd of CS pin

To prevent mistake in operation and mistake write at power ON/OFF, CS pull down resistance is necessary. Select an appropriate value to this resistance value from microcontroller VOH, IOH, and VIL characteristics of this IC.

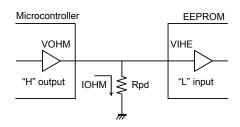


Fig.37 CS pull down resistance

$$\mathsf{Rpd} \; \geqq \; \frac{\mathsf{VOHM}}{\mathsf{IOHM}} \quad \cdot \quad \cdot \quad \textcircled{1}$$

$$\mathsf{VOHM} \; \geqq \; \mathsf{VIHE} \qquad \cdot \quad \cdot \quad \textcircled{2}$$

Example) When V_{CC} =5V, VIHE=2V, VOHM=2.4V, IOHM=2mA, from the equation ①,

$$Rpd \ge \frac{2.4}{2 \times 10^{-3}}$$

$$\therefore$$
 Rpd \geq 1.2 [k Ω]

With the value of Rpd to satisfy the above equation, VOHM becomes 2.4V or higher, and VIHE (=2.0V), the equation ② is also satisfied.

VIHE : EEPROM VIH specifications
 VOHM : Microcontroller VOH specifications
 IOHM : Microcontroller IOH specifications

4-2) DO is available in both pull up and pull down.

Do output become "High-Z" in other READY / BUSY output timing than after data output at read command and write command. When malfunction occurs at "High-Z" input of the microcontroller port connected to DO, it is necessary to pull down and pull up DO. When there is no influence upon the microcontroller actions, DO may be OPEN. If DO is OPEN, and at timing to output status READY, at timing of CS="H", SK="H", DI="H", EEPROM recognizes this

as a start bit, resets READY output, and DO="High-Z", therefore, READY signal cannot be detected. To avoid such output, pull up DO pin for improvement.

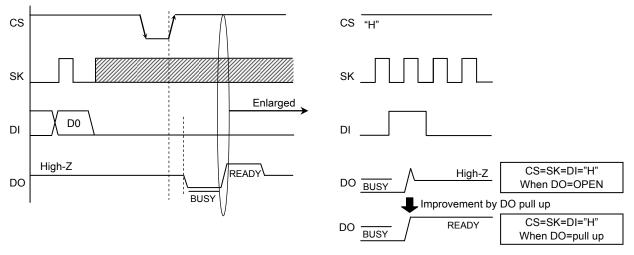


Fig.38 READY output timing at DO=OPEN

OPull up resistance Rpu and pull down resistance Rpd of DO pin

As for pull up and pull down resistance value, select an appropriate value to this resistance value from microcontroller VIH, VIL, and VOH, IOH, VOL, IOL characteristics of this IC.

∴.

VOLE

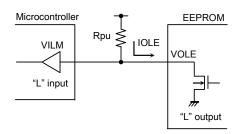


Fig.39 DO pull up resistance

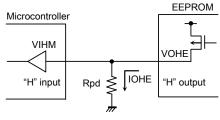


Fig.40 DO pull down resistance

Rpu
$$\geq$$
 \cdots $\widehat{3}$
VOLE \leq VILM \cdots $\widehat{4}$

Example) When V_{CC} =5V, VOLE=0.4V, IOLE=2.1mA, VILM=0.8V, from the equation 3,

Rpu
$$\geqq$$
 Rpu \geqq 2.2 [k Ω]

With the value of Rpu to satisfy the above equation, VOLE becomes 0.4V or below, and with VILM(=0.8V), the equation 4 is also satisfied. : EEPROM VOL specifications

> IOLE : EEPROM IOL specifications VILM : Microcontroller VIL specifications VOHE Rpd

$$Rpd \ge \frac{VOHE}{IOHE} \cdots \$$$

$$VOHE \ge VIHM \cdots \$$$

Example) When V_{CC} =5V, VOHE=Vcc-0.2V, IOHE=0.1mA, VIHM=Vcc×0.7V from the equation ⑤,

$$\mathsf{Rpd} \; \geqq \quad \frac{5 - 0.2}{0.1 \times 10^{-3}}$$

$$\therefore \qquad \mathsf{Rpd} \; \geqq \; 48 \, [\mathsf{k}\Omega]$$

With the value of Rpd to satisfy the above equation, VOHE becomes 2.4V or below, and with VIHM (=3.5V), the equation ⑥ is also satisfied.

> VOHE : EEPROM VOH specifications IOHE : EEPROM IOH specifications VIHM : Microcontroller VIH specifications

5) READY / BUSY status display (DO terminal)

(common to BR93L46-W / A46-WM, BR93L56-W / A56-WM, BR93L66-W / A66-WM, BR93L76-W / A76-WM, BR93L86-W / A86-WM)

This display outputs the internal status signal. When CS is started after tCS (Min.200ns)

from CS fall after write command input, "H" or "L" is output.

$$R/\overline{B}$$
 display="L" (\overline{BUSY}) = write under execution

After the timer circuit in the IC works and creates the period of tE/W, this time circuit completes automatically. And write to the memory cell is made in the period of tE/W, and during this period, other command is not accepted.

$$R/B$$
 display = "H" (READY) = command wait status

Even after tE/W (max.5ms) from write of the memory cell, the following command is accepted.

Therefore, CS="H" in the period of tE/W, and when input is in SK, DI, malfunction may occur, therefore, DI="L" in the area

CS="H". (Especially, in the case of shared input port, attention is required.)

* Do not input any command while status signal is output.

Command input in BUSY area is cancelled, but command input in READY area is accepted.

Therefore, status READY output is cancelled, and malfunction and mistake write may be made.

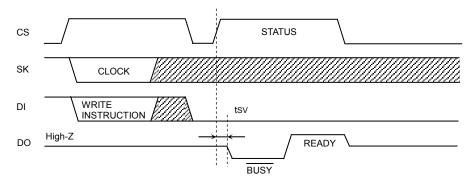


Fig.41 R/B status output timing chart

6) When to directly connect DI and DO

This IC has independent input terminal DI and output terminal DO, and separate signals are handled on timing chart, meanwhile, by inserting a resistance R between these DI and DO terminals, it is possible to carry out control by 1 control line

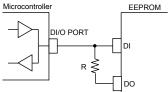


Fig.42 DI, DO control line common connection

OData collision of microcontroller DI/O output and DO output and feedback of DO output to DI input.

Drive from the microcontroller DI/O output to DI input on I/O timing, and signal output from DO output occur at the same time in the following points.

- 1 clock cycle to take in A0 address data at read command Dummy bit "0" is output to DO terminal.
 - →When address data A0 = "1" input, through current route occurs.

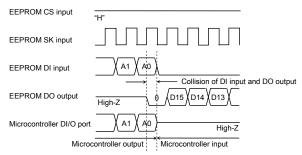


Fig.43 Collision timing at read data output at DI, DO direct connection

(2) Timing of CS = "H" after write command. DO terminal in READY / BUSY function output.

When the next start bit input is recognized, "HIGH-Z" gets in.

→Especially, at command input after write, when CS input is started with microcontroller DI/O output "L", READY output "H" is output from DO terminal, and through current route occurs.

Feedback input at timing of these (1) and (2) does not cause disorder in basic operations, if resistance R is inserted.

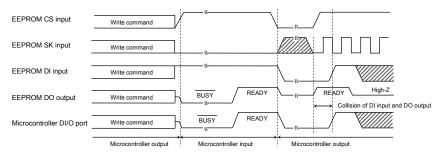


Fig.44 Collision timing at DI, DO direct connection

Note) As for the case (2), attention must be paid to the following.

When status READY is output, DO and DI are shared, DI="H" and the microcontroller DI/O="High-Z" or the microcontroller DI/O="H",if SK clock is input, DO output is input to DI and is recognized as a start bit, and malfunction may occur. As a method to avoid malfunction, at status READY output, set SK="L", or start CS within 4 clocks after "H" of READY signal is output.

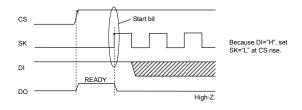
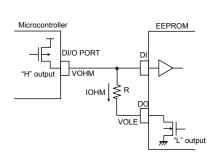


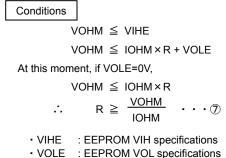
Fig.45 Start bit input timing at DI, DO direct connection

OSelection of resistance value R

The resistance R becomes through current limit resistance at data collision. When through current flows, noises of power source line and instantaneous stop of power source may occur. When allowable through current is defined as I, the following relation should be satisfied. Determine allowable current amount in consideration of impedance and so forth of power source line in set. And insert resistance R, and set the value R to satisfy EEPROM input level VIH/VIL even under influence of voltage decline owing to leak current and so forth. Insertion of R will not cause any influence upon basic operations.

- (1) Address data A0 = "1" input, dummy bit "0" output timing (When microcontroller DI/O output is "H", EEPROM DO outputs "L", and "H" is input to DI)
 - Make the through current to EEPROM 10mA or below.
 - · See to it that the level VIH of EEPROM should satisfy the following.





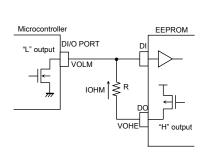
VOLE : EEPROM VOL specifications
 VOHM : Microcontroller VOH specifications
 IOHM : Microcontroller IOH specifications

Fig.46 Circuit at DI, DO direct connection (Microcontroller DI/O "H" output, EEPROM "L" output)

(2) DO status READY output timing

(When the microcontroller DI/O is "L", EEPROM DO output "H", and "L" is input to DI)

· Set the EEPROM input level VIL so as to satisfy the following.



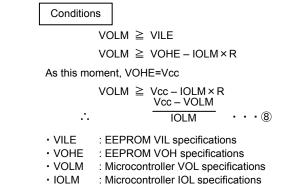


Fig.47 Circuit at DI, DO direct connection (Microcontroller DI/O "L" output, EEPROM "H" output)

Example) When Vcc=5V, VOHM=5V, IOHM=0.4mA, VOLM=5V, IOLM=0.4mA,

From the equation 7,

$$R \ge \frac{\text{VOHM}}{\text{IOHM}}$$

$$R \ge \frac{5}{0.4 \times 10^{-3}}$$

$$R \ge 12.5 [k\Omega] \cdots 9$$

$$R \ge \frac{\text{Vcc} - \text{VOLM}}{\text{IOLM}}$$

$$R \ge \frac{5 - 0.4}{2.1 \times 10^{3}}$$

$$R \ge 2.2 [k\Omega] \cdots 0$$

Therefore, from the equations (9) and (10),

$$\therefore$$
 R \geq 12.5 [k Ω]

∴.

7) Notes on power ON/OFF

· At power ON/OFF, set CS "L".

When CS is "H", this IC gets in input accept status (active). If power is turned on in this status, noises and the likes may cause malfunction, mistake write or so. To prevent these, at power ON, set CS "L". (When CS is in "L" status, all inputs are cancelled.) And at power decline, owing to power line capacity and so forth, low power status may continue long. At this case too, owing to the same reason, malfunction, mistake write may occur, therefore, at power OFF too, set CS "L".

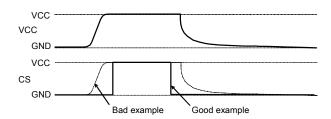


Fig.48 Timing at power ON/OFF

(Bad example) CS pin is pulled up to Vcc.

In this case, CS becomes "H" (active status), and EEPROM may have malfunction, mistake write owing to noise and the likes.

Even when CS input is High-Z, the status becomes like this case, which please note.

(Good example) It is "L" at power ON/OFF.

Set 10ms or higher to recharge at power OFF.

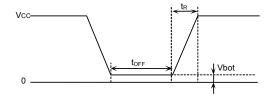
When power is turned on without observing this condition,

IC internal circuit may not be reset, which please note.

OPOR citcuit

This IC has a POR (Power On Reset) circuit as a mistake write countermeasure. After POR action, it gets in write disable status. The POR circuit is valid only when power is ON, and does not work when power is OFF. However, if CS is "H" at power ON/OFF, it may become write enable status owing to noises and the likes. For secure actions, observe the follwing conditions.

- 1. Set CS="L"
- 2. Turn on power so as to satisfy the recommended conditions of tR, tOFF, Vbot for POR circuit action.



Recommended conditions of tR, toff, Vbot

t_R	t_{OFF}	Vbot
10ms or below	10ms or higher	0.3V or below
100ms or below	10ms or higher	0.2V or below

Fig.49 Rise waveform diagram

OLVCC circuit

LVCC (VCC-Lockout) circuit prevents data rewrite action at low power, and prevents wrong write. At LVCC voltage (Typ.=1.2V) or below, it prevent data rewrite.

8) Noise countermeasures

OVCC noise (bypass capacitor)

When noise or surge gets in the power source line, malfunction may occur, therefore, for removing these, it is recommended to attach a bypass capacitor (0.1 μ F) between IC VCC and GND, At that moment, attach it as close to IC as possible. And, it is also recommended to attach a bypass capacitor between board VCC and GND.

OSK noise

When the rise time (tR) of SK is long, and a certain degree or more of noise exists, malfunction may occur owing to clock bit displacement. To avoid this, a Schmitt trigger circuit is built in SK input. The hysteresis width of this circuit is set about 0.2V, if noises exist at SK input, set the noise amplitude 0.2Vp-p or below. And it is recommended to set the rise time (tR) of SK 100ns or below. In the case when the rise time is 100ns or higher, take sufficient noise countermeasures. Make the clock rise, fall time as small as possible.

Notes for use

- (1) Described numeric values and data are design representative values, and the values are not guaranteed.
- (2) We believe that application circuit examples are recommendable, however, in actual use, confirm characteristics further sufficiently. In the case of use by changing the fixed number of external parts, make your decision with sufficient margin in consideration of static characteristics and transition characteristics and fluctuations of external parts and our LSI.
- (3) Absolute Maximum Ratings

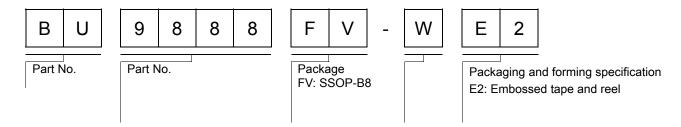
If the absolute maximum ratings such as impressed voltage and action temperature range and so forth are exceeded, LSI may be destructed. Do not impress voltage and temperature exceeding the absolute maximum ratings. In the case of fear exceeding the absolute maximum ratings, take physical safety countermeasures such as fuses, and see to it that conditions exceeding the absolute maximum ratings should not be impressed to LSI.

- (4) GND electric potential
 - Set the voltage of GND terminal lowest at any action condition. Make sure that each terminal voltage is not lower than that of GND terminal in consideration of transition status.
- (5) Heat design

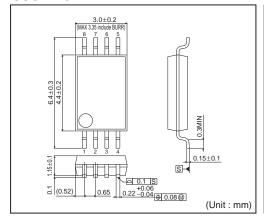
In consideration of allowable loss in actual use condition, carry out heat design with sufficient margin.

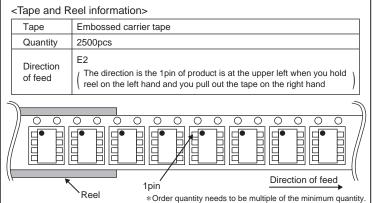
- (6) Terminal to terminal short-circuit and wrong packaging When to package LSI onto a board, pay sufficient attention to LSI direction and displacement. Wrong packaging may destruct LSI. And in the case of short-circuit between LSI terminals and terminals and power source, terminal and GND owing to foreign matter, LSI may be destructed.
- (7) Use in a strong electromagnetic field may cause malfunction, therefore, evaluate design sufficient.

Ordering part number



SSOP-B8





Notes

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